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Schottky Barrier Rectifier, Trench-based, High Performance

NRTS6100PFS, NRVTS6100PFS

This Trench Schottky rectifier is a high performance device in a TO-277 package. The lower forward voltage, less leakage current, and small junction capacitance are suitable to high switching frequency high density DC to DC conversion applications. It offers higher avalanche energy capability for Oring or reverse protection applications. The TO-277 package provides excellent thermal performance, less land area of board space, and a low profile.

Features

- Lower Forward Voltage Drop
- Less Leakage Current in High Temperature
- Small Junction Capacitance for High Switching Frequency
- Higher Avalanche Energy Capability
- 175°C Operating Junction Temperature
- Package Provided Capability of Inspection and Probe After Board Mounting
- Good Alternative Solution of SMC and DPAK Package

Mechanical Characteristics:

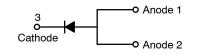
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements
- ESD Ratings:
 - Human Body Model: \geq 8000 V (Class 3B)
 - Charged Device Model: > 1000 V (Class C5)

Applications

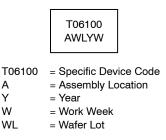
- High Switching Frequency DC/DC Converters
- 2nd Rectifier
- Oring / Reverse Protection
- Freewheeling Diode for Inductive Loads







MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping†
NRTS6100PFST3G	TO–277 (Pb–Free)	1500 / Tape & Reel
NRVTS6100PFST3G	TO–277 (Pb–Free)	1500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V
Continuous Forward Current $(T_C = 168^{\circ}C, DC)$	I _{F(DC)}	6	A
Peak Repetitive Forward Current, ($T_C = 166^{\circ}C$, Square Wave, Duty = 0.5)	I _{FRM}	12	A
Non-Repetitive Avalanche Energy $(T_J = 25^{\circ}C)$	E _{AS}	145	mJ
Storage Temperature Range	T _{stg}	−65 to +175	°C
Operating Junction Temperature (Note 1)	TJ	–55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient $dP_D/dT_J < 1/R_{\theta JA}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	70	°C/W
Thermal Resistance, Junction-to-Case Bottom	$R_{\theta JCB}$	2.2	°C/W
Thermal Characterization, Junction-to-Case Top	Ψ_{JCT}	1.1	°C/W
Thermal Characterization, Junction-to-Lead of Cathode	Ψ_{JLC}	0.7	°C/W

NOTE: (Assumes 600 mm², 1 oz. copper bond pad on a FR4 board)

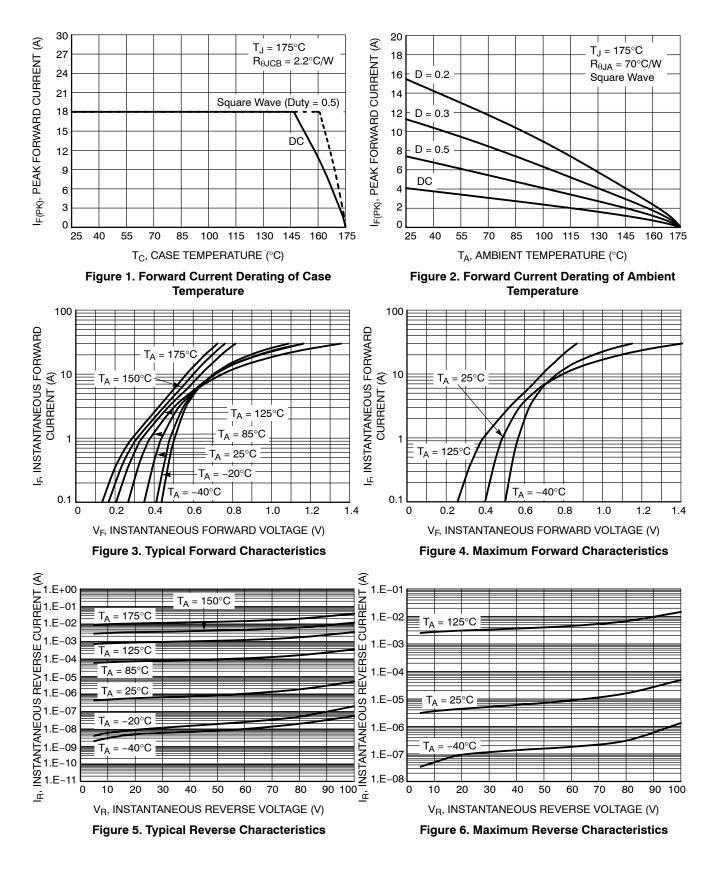
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Тур	Max	Unit
$ \begin{array}{l} \mbox{Instantaneous Forward Voltage (Note 2)} \\ (I_F = 3 \ A, \ T_J = 25^{\circ} C) \\ (I_F = 3 \ A, \ T_J = 125^{\circ} C) \\ (I_F = 6 \ A, \ T_J = 25^{\circ} C) \\ (I_F = 6 \ A, \ T_J = 125^{\circ} C) \end{array} $	V _F	0.52 0.47 0.62 0.56	 0.68 0.62	V
Instantaneous Reverse Current (Note 2) (V _R = Rated DC Voltage, $T_J = 25^{\circ}$ C) (V _R = Rated DC Voltage, $T_J = 125^{\circ}$ C)	I _R	6.2 3.3	50 15	μA mA
Junction Capacitance $(V_R = 1 V, T_J = 25^{\circ}C, 1 MHz)$	CJ	827	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

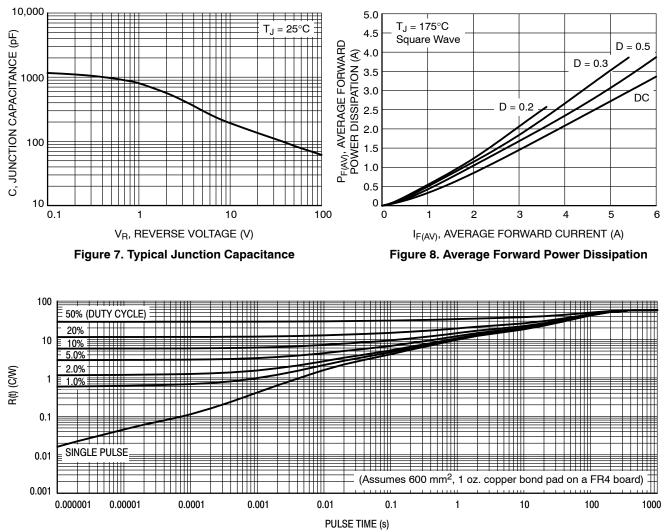


Figure 9. Typical Thermal Characteristics, Junction-to-Ambient

PACKAGE DIMENSIONS

TO-277-3LD

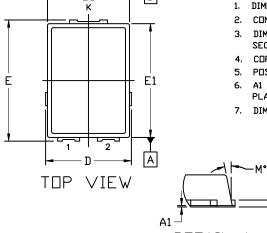
CASE 340CZ **ISSUE A**

С

NDTES:

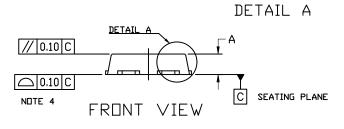
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
 - DIMENSIONS b, b1,b2,b3,b6 AND c TO BE MEASURED ON FLAT
 - SECTION OF THE LEAD, BETWEEN 0.13 AND 0.25mm FROM LEAD TIP.
- COPLANARITY APPLES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
- 5. POSITIONAL TOLERANCE APPLIES TO THE TERMINALS AND EXPOSED PAD.
 - A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING
- PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

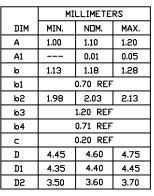
7. DIMENSIONS D AND E TO BE DETERMINED AT DATUM PLANE C.



В

D1





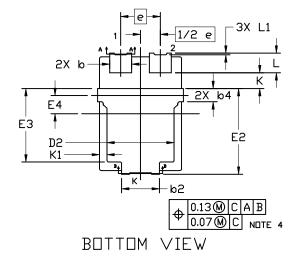
	MILLIMETERS		
DIM	MIN.	NDM.	MAX.
E	6.35	6.50	6.65
E1	6.05	6.10	6.15
E2	4.50	4.60	4.70
E3	3.84	3.94	4.04
E4	0.98 REF		
e	2.13 BSC		
к	0.85 REF		
К1	0.40 REF		
L	0.90	1.05	1.20
L1	0.02		
м			12*

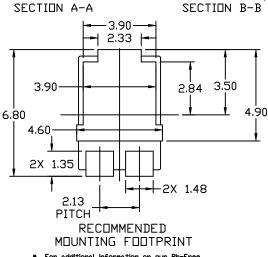












For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/J.

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